# NSN 5961-01-069-9732

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#### **Inclosure Material:**

Metal

# **Overall Length:**

Between 0.250 inches and 0.340 inches

# **Overall Diameter:**

0.620 inches

# **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-66

Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Npn

#### Mounting Method:

Unthreaded hole

#### Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

70.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

Between 2.00 amperes source cutoff current and 4.00 amperes source cutoff current

# Power Rating Per Characteristic:

25.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

#### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# Terminal Type And Quantity:

1 case and 2 pin

**Specification Data:** 

81349-mil-s-19500/518 government specification

Shelf Life:

N/a

Unit Of Measure:

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- Demilitarization:

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